

KTK 840	Kec	MOS-N-FET-e	VFET, 450V, 8A, 125W, on<0,75Ω(8A), <500/1000ns	17p	TO-220			IRF 840, 2SK894, 2SK1495...96, 2SK1574
KTK 930	Kec	MOS-N-FET-e	VFET, 900V, 5A, 150W, on<3Ω(5A), <260/900ns	77p	TOP-3L			2SK539, 2SK1465
KTK 1021	Kec	MOS-N-FET-e	=KTK 821: Iso	17c	TO-220 Iso			BUK 445-450, 2SK1444, 2SK1862...63,++
KTK 1031	Kec	MOS-N-FET-e	=KTK 831: Iso	17c	TO-220 Iso			2SK1231, 2SK1351, 2SK1445, 2SK1990...91++
KTK 1040	Kec	MOS-N-FET-e	=KTK 840: Iso	17c	TO-220 Iso			2SK1352, 2SK1446, 2SK1609, 2SK1566...67++
KTK 1140	Kec	MOS-N-FET-e	=KTK 740: Iso	17c	TO-220 Iso			2SK2363...64
KTN 2222(A)	Kec	Si-N	=2N2222(A): 0,625W	7c	TO-92		*2N2222	
KTN 2222(A)S	Kec	Si-N	=2N2222(A): SMD	35a	SOT-23			BSR14, BSS79, PMBT2222(A), SMBT2222(A)
KTN 2369(A)	Kec	Si-N	=2N2369(A): 0,625W	7c	TO-92		*2N2369	
KTN 2369(A)	Kec	Si-N	=2N2369(A): SMD	35a	SOT-23			2SC4168, PMBT 2369(A)
KTN 2907(A)	Kec	Si-P	=2N2907(A): 0,625W	7c	TO-92		*2N2907	
KTN 2907(A)	Kec	Si-P	=2N2907(A): SMD	35a	SOT-23			BSR15...16, BSS80, PMBT2907(A), SMBT2907(A)
KTQ 127	Kec	MOS-N-FET-d	=3SK127:	44l	SOT-143			*3SK127
KTY 13	Sie	Si-Sensor	SMD, Temperatur-Sensor	35	SOT-23			
KTY 81-110...-152	Phi	Si-Sensor	Temperatur-Sensor, 1kΩ(1mA/25°), -55...+150°	7	SOD-70			
KTY 81-210...-252	Phi	Si-Sensor	Temperatur-Sensor, 2kΩ(1mA/25°), -55...+150°	7	SOD-70			
KTY 82-...	Phi	Si-Sensor	=KTY 81-...: SMD	35	SOT-23			
KTY 83-110...-152	Phi	Si-Sensor	Temperatur-Sensor, 1kΩ(1mA/25°), -55...+175°	31	DO-34			
KTY 83-130...-152	Phi	Si-Sensor	Temperatur-Sensor, 1kΩ(2mA/100°), -40...+300°	31	DO-34			
KTY 85-110...-152	Phi	Si-Sensor	Temperatur-Sensor, 1kΩ(1mA/25°), -40...+125°	72(3,4mm)	SOD-80			
KTY 86-205	Phi	Si-Sensor	Temperatur-Sensor, 2kΩ(0,1mA/25°), -40...+150°		SOD-103			
KTY 87-205	Phi	Si-Sensor	Temperatur-Sensor, 2kΩ(0,1mA/25°), -40...+125°		SOD-103			

KU

KU 601	Tes	Si-N	S P, 60V, 2A, 10W(Tc=105°), 15MHz	23a	TO-3	2N3055	23a	BUX 16, 2SC2809
KU 602	Tes	Si-N	S P, 100V, 2A, 10W(Tc=105°), 15MHz	23a	TO-3	2N3055	23a	BUX 16, 2SC2809
KU 605	Tes	Si-N	S P, 200V, 10A, 50W(Tc=80°), 5MHz	23a	TO-3	(BU 608)7	23a	BU 109, BUX 17, TIP 160, 2SC2769, ++
KU 606	Tes	Si-N	S P, 120V, 8A, 50W(Tc=80°), 5MHz	23a	TO-3	BU 608	23a	BU 109, BUX 17, TIP 160, 2SC2769, ++
KU 607	Tes	Si-N	S P, 210V, 10A, 70W(Tc=45°)	23a	TO-3	(BU 608)7	23a	BU 109, BUX 17, TIP 160, 2SC2769, ++
KU 608	Tes	Si-N	250V, 10A, 70W(Tc=45°), 9MHz	23a	TO-3	(BU 608)7	23a	BU 109, BUX 17, TIP 160, 2SC2769, ++
KU 611	Tes	Si-N	S P, 60V, 3A, 10W(Tc=105°), 30MHz	22a	TO-66	BD 243 C	17j	BD 241B, BD 243B, BU 409, 2SD422...423,++
KU 612	Tes	Si-N	S P, 120V, 3A, 10W(Tc=105°), 30MHz	22a	TO-66	BD 243 C	17j	BD 241C, BD 243C, BU 409, 2SD422...423,++

KV...KZ

KV		PIN-Di	=1SV264 (SMD-Marking)	35 (2mm)	SOT-323			*1SV264
KV		PIN-Di	=1SV267 (SMD-Marking)	35	SOT-23			*1SV267
KX		MOS-N-FET-e	=PMBF 170 (SMD-Marking)	35	SOT-23			*PMBF 170
KX-1		Si-Di	=BAV 20			BA 159	31a	*BAV 20
KY		Si-N	=2SC3771 (SMD-Marking)	35	SOT-23			*2SC3771
KY		N-FET	=2SK211-Y (SMD-Marking)	35	SOT-23			*2SK211
KY		N-FET	=2SK881-Y (SMD-Marking)	35(2mm)	SOT-323			*2SK881
KY		Si-P	=KTA1001-Y (SMD-Marking)	39	SOT-89			*KTA 1001
KY		N-FET	=KTK 211-Y (SMD-Marking)	35	SOT-23			*KTK 211
KY 701		Si-Di		31a		1N4007	31a	

L

L		Si-N	=2SC4211 (SMD-Marking)	35(2mm)	SOT-323			*2SC4211
L		GaAs-N-FET	=2SK1689 (Marking)	51	SOT-173			*2SK1689
L		GaAs-N-FET	=2SK690 (SMD-Marking)	39	SOT-89			*2SK690
L 1		Si-N	=BFS 36 (SMD-Marking)	35(2mm)	SOT-323			*BFS 36
L 1		Si-P	=BSS 65 (SMD-Marking)	35	SOT-23			*BSS 65
L 1 G		Si-N	=HN 2C01FU-GR (SMD-Marking)	46(2mm)	SOT-363			*HN 2C01FU
L 1 X		N-FET	=KSK 123: (SMD-Marking)	35	SOT-23			*2SK123
L 1 Y		Si-N	=HN 2C01FU-Y (SMD-Marking)	46(2mm)	SOT-363			*HN 2C01FU
L 2		Si-N	=BFS 36A (SMD-Marking)	35(2mm)	SOT-323			*BFS 36A
L 2		Si-P	=BSS 69 (SMD-Marking)	35	SOT-23			*BSS 69
L 2 X		N-FET	=KSK 211: (SMD-Marking)	35	SOT-23			*2SK211
L 3		Si-N	=2SC1623-L3 (SMD-Marking)	35	SOT-23			*2SC1623
L 3		Si-P	=BFS 37 (SMD-Marking)	35(2mm)	SOT-323			*BFS 37
L 3		Si-P	=BSS 70 (SMD-Marking)	35	SOT-23			*BSS 70
L 4		Si-N	=2SC1623-L4 (SMD-Marking)	35	SOT-23			*2SC1623
L 4		Si-N	=2SC2812-L4 (SMD-Marking)	35	SOT-23			*2SC2812
L 4		Si-N	=2SC4177-L4 (SMD-Marking)	35(2mm)	SOT-323			*2SC4177
L 4		Si-N	=2SC4783-L4 (SMD-Marking)	35(1,6mm)	SS Mini			*2SC4783
L 4(p)		Si-Di	=BAT 54 (SMD-Marking)	35	SOT-23			*BAT 54
L 4		Si-Di	=BAT 54W (SMD-Marking)	35(2mm)	SOT-323			*BAT 54W
L 4		Si-P	=BFS 37A (SMD-Marking)	35(2mm)	SOT-323			*BFS 37A
L 4		Si-P	=BSS 65R (SMD-Marking)	35	SOT-23			*BSS 65R
L 005(T1)	Sgs	Z-IC	+5V, 0,93A	23a	TO-3	7805/TO-3	23a	*7805... (TO-3)
L 5		Si-N	=2SC1623-L5 (SMD-Marking)	35	SOT-23			*2SC1623
L 5		Si-N	=2SC2812-L5 (SMD-Marking)	35	SOT-23			*2SC2812
L 5		Si-N	=2SC4177-L5 (SMD-Marking)	35(2mm)	SOT-323			*2SC4177
L 5		Si-N	=2SC4783-L5 (SMD-Marking)	35(1,6mm)	SS Mini			*2SC4783
L 5(p)		Si-Di	=BAS 55 (SMD-Marking)	35	SOT-23			*BAS 55
L 5		Si-N	=BFT 27 (SMD-Marking)	35(2mm)	SOT-323			*BFT 27
L 5		Si-P	=BSS 69R (SMD-Marking)	35	SOT-23			*BSS 69R
L 6		Si-N	=2SC1623-L6 (SMD-Marking)	35	SOT-23			*2SC1623
L 6		Si-N	=2SC2812-L6 (SMD-Marking)	35	SOT-23			*2SC2812
L 6		Si-N	=2SC4177-L6 (SMD-Marking)	35(2mm)	SOT-323			*2SC4177
L 6		Si-N	=2SC4783-L6 (SMD-Marking)	35(1,6mm)	SS Mini			*2SC4783
L 6		PIN-Di	=BAR 17 (SMD-Marking)	35	SOT-23			*BAR 17
L 6		Si-N	=BSS 47 (SMD-Marking)	35(2mm)	SOT-323			*BSS 47
L 6		Si-P	=BSS 70R (SMD-Marking)	35	SOT-23			*BSS 70R
L 7		Si-N	=2SC1623-L7 (SMD-Marking)	35	SOT-23			*2SC1623
L 7		Si-N	=2SC2812-L7 (SMD-Marking)	35	SOT-23			*2SC2812
L 7		Si-N	=2SC4177-L7 (SMD-Marking)	35(2mm)	SOT-323			*2SC4177
L 7		Si-N	=2SC4783-L7 (SMD-Marking)	35(1,6mm)	SS Mini			*2SC4783
L 7		PIN-Di	=BAR 14-1 (SMD-Marking)	35	SOT-23			*BAR 14
L 7		Si-N	=BSS 56 (SMD-Marking)	35(2mm)	SOT-323			*BSS 56
L 8		PIN-Di	=BAR 15-1 (SMD-Marking)	35	SOT-23			*BAR 15
L 9		Si-Di	=1SS349 (SMD-Marking)	35	SOT-23			*1SS349
L 9		PIN-Di	=BAR 16-1 (SMD-Marking)	35	SOT-23			*BAR 16
L 15		Si-N	=2SC3624A-L15 (SMD-Marking)	35	SOT-23			*2SC3624A